

## Turbo 2 ultrafast high voltage rectifier



#### **Features**

- High junction temperature capability
- · Ultrafast with soft recovery behavior
- Low reverse current
- · Low thermal resistance
- · reduced switching and conduction losses

## **Description**

The STTH60RQ06 has been developed for applications requiring a high-voltage secondary rectification for LLC full bridge topology.

Also it is ideal for switching power supplies and industrial applications, as rectification, freewheeling and clamping diode.

Product status link		
STTH60RQ06		
Product summary		
Symbol Value		
I <sub>F(AV)</sub>	60 A	
V <sub>RRM</sub>	600 V	
V <sub>F</sub> (max.)	1.45 V	
t <sub>rr</sub> (max.)	35 ns	
T <sub>j</sub> (max.)	175 °C	



## 1 Characteristics

Table 1. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Parameter	Value	Unit	
V <sub>RRM</sub>	Repetitive peak reverse voltage	600	V	
I <sub>F(RMS)</sub>	Forward rms current	Forward rms current 90 A		
I <sub>F(AV)</sub>	Average forward current	60	Α	
I <sub>FSM</sub>	Surge non repetitive forward current	425	Α	
T <sub>stg</sub>	Storage temperature range	-65 to +175	°C	
Tj	Maximum operating junction temperature 175			°C

**Table 2. Thermal resistance parameters** 

Symbol	Parameter	Max.	Unit
R <sub>th(j-c)</sub>	Junction to case	0.38	°C/W

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
1 (1)	T <sub>j</sub> = 25 °C		-		80		
'R''	I <sub>R</sub> <sup>(1)</sup> Reverse leakage current	T <sub>j</sub> = 150 °C	$V_R = V_{RRM}$	-	160	1600	μA
	V (2)	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 30 A	-		2.45	
V <sub>F</sub> <sup>(2)</sup>		T <sub>j</sub> = 150 °C		-	1.15	1.45	V
V <sub>F</sub> <sup>(2)</sup> Forward voltage drop	T <sub>j</sub> = 25 °C	I 60 A	-		2.95	V	
		T <sub>j</sub> = 150 °C	I <sub>F</sub> = 60 A	-	1.45	1.85	

- 1. Pulse test: tp = 5 ms,  $\delta < 2\%$
- 2. Pulse test:  $tp = 380 \ \mu s, \ \delta < 2\%$

To evaluate the conduction losses, use the following equation:

$$P = 1.05 \text{ x } I_{F(AV)} + 0.013 \text{ x } I_{F}^{2}_{(RMS)}$$

Table 4. Dynamic electrical characteristics

Symbol	Parameter	Test conditions			Тур.	Max.	Unit
+	t Doverno recovery time T.		T <sub>i</sub> = 25 °C			35	no
Yrr	$t_{rr}$ Reverse recovery time $T_j$ :	1] - 23 0	$I_F = 1 \text{ A}, V_R = 30 \text{ V}, dI_F/dt = -50 \text{ A/}\mu\text{s}$	-	50	65	ns
I <sub>RM</sub>	Reverse recovery current		$I_F = 60 \text{ A}, V_R = 400 \text{ V}, dI_F/dt = -200 \text{ A/}\mu\text{s}$	-	12	16	Α
Q <sub>rr</sub>	Reverse recovery charge	T <sub>j</sub> = 125 °C		-	660		nC
t <sub>rr</sub>	Reverse recovery time			-	92		ns

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#### 1.1 Characteristics (curves)

Figure 1. Average forward power dissipation versus average forward current (square waveform)

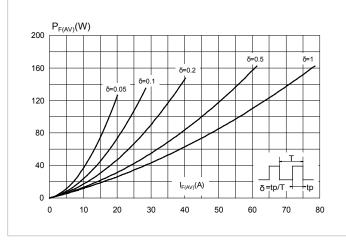


Figure 2. Average forward power dissipation versus average forward current (sinusoidal waveform)

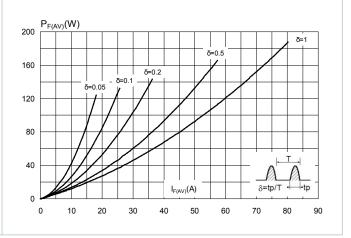


Figure 3. Forward voltage drop versus forward current (typical values)

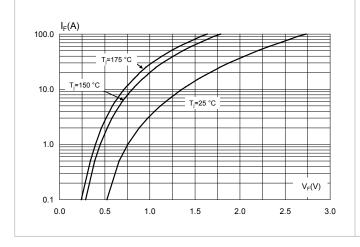


Figure 4. Forward voltage drop versus forward current (maximum values)

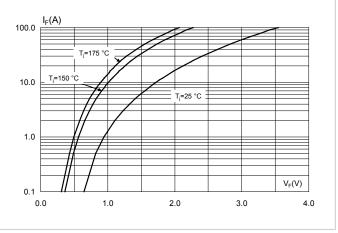


Figure 5. Relative variation of thermal impedance junction to case versus pulse duration

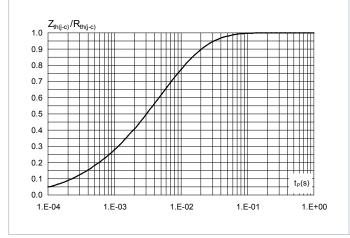
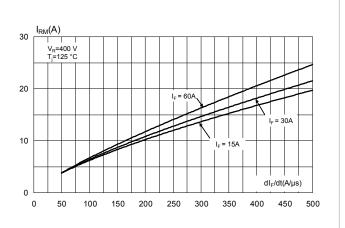


Figure 6. Peak reverse recovery current versus dl<sub>F</sub>/dt (typical values)



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Figure 7. Reverse recovery time versus dl<sub>F</sub>/dt (typical values)

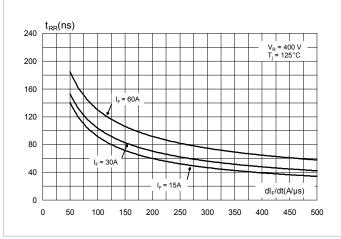


Figure 8. Reverse recovery charges versus dl<sub>F</sub>/dt (typical values)

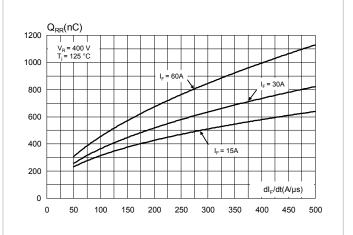


Figure 9. Reverse recovery softness factor versus dl<sub>F</sub>/dt (typical values)

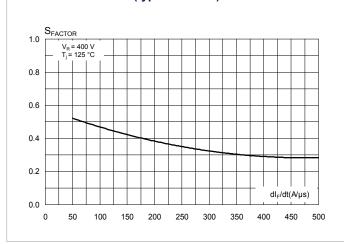


Figure 10. Relative variations of dynamic parameters versus junction temperature

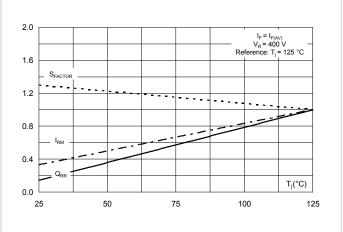


Figure 11. Junction capacitance versus reverse voltage applied (typical values)

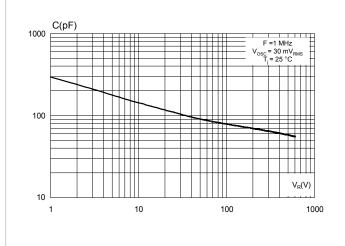
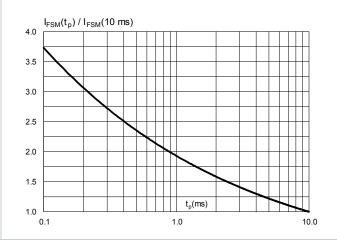


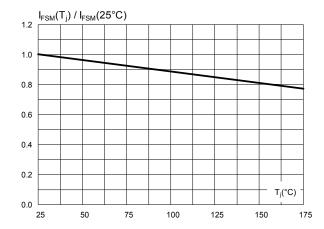
Figure 12. Relative variation of non-repetitive peak surge forward current versus pulse duration (sinusoidal waveform)



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Figure 13. Relative variation of non-repetitive peak surge forward current versus initial junction temperature (sinusoidal waveform)



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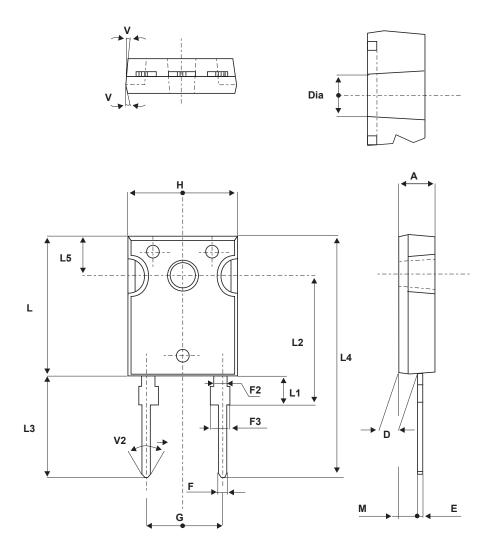
## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

## 2.1 DO-247 package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.8 N·m (DO-247)
- Maximum torque value: 1.0 N·m (DO-247)

Figure 14. DO-247 package outline



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Table 5. DO-247 package mechanical data

	Dimensions				
Ref.	Millimeters		Inch	es	
	Min.	Max.	Min.	Max.	
А	4.85	5.15	0.191	0.203	
D	2.20	2.60	0.086	0.102	
E	0.40	0.80	0.015	0.031	
F	1.00	1.40	0.039	0.055	
F2	2.00	typ.	0.078	typ.	
F3	2.00	2.40	0.078	0.094	
G	10.90 typ.		0.429 typ.		
Н	15.45	15.75	0.608	0.620	
L	19.85	20.15	0.781	0.793	
L1	3.70	4.30	0.145	0.169	
L2	18.50	typ.	0.728 typ.		
L3	14.20	14.80	0.559	0.582	
L4	34.60	34.60 typ.		typ.	
L5	5.50 typ.		0.216	typ.	
М	2.00	3.00	0.078	0.118	
V	5°		5°	•	
V2	60	O°	60	0	
Dia.	3.55	3.65	0.139	0.143	



# **3** Ordering information

**Table 6. Ordering information** 

Order code	Marking	Package Weight		Base qty.	Delivery mode
STTH60RQ06W	STTH60RQ06W	DO-247	4.40 g	30	Tube

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## **Revision history**

Table 7. Document revision history

Date	Version	Changes
03-Apr-2018	1	Initial release.

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